A Product Line of Diodes Incorporated | LITE-ON SEMICONDUCTOR

ES1D-ES1J(LS)

SURFACE MOUNT SUPER FAST RECTIFIERS

REVERSE VOLTAGE – 200 to 600 Volts FORWARD CURRENT – 1.0 Ampere

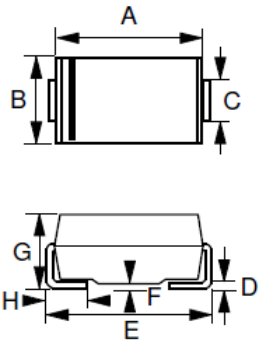
FEATURES

- Glass passivated chip
- Super fast switching for high efficiency
- For surface mounted applications
- Low forward voltage drop and high current capability
- Low reverse leakage current
- Qualified according to AEC-Q101 Rev_C
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

MECHANICAL DATA

- Case : Molded plastic
- Case Material: Molding compound, UL Flammability classification 94V-0,"Halogen-free".
- Polarity : Indicated by cathode band
- Weight : 0.002 ounces, 0.064 grams

SMA



SMA		
DIM	MIN	MAX
A	4.06	4.57
B	2.29	2.92
C	1.27	1.63
D	0.15	0.31
E	4.83	5.59
F	0.05	0.20
G	2.01	2.40
H	0.76	1.52
All dimension in millimeter		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

PARAMETER	SYMBOL	ES1D	ES1G	ES1J	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	200	400	600	V
Maximum RMS Voltage	V_{RMS}	140	280	420	V
Maximum DC Blocking Voltage	V_{DC}	200	400	600	V
Maximum Average Forward Rectified Current @T_L=110°C	$I_{(AV)}$	1.0			A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD)	I_{FSM}	30			A
Maximum forward Voltage at 1.0A DC	V_F	0.92	1.25	1.30	V
Maximum DC Reverse Current at Rated DC Blocking Voltage @ T_J=25°C @ T_J=125°C	I_R	5.0 200			uA
Maximum Reverse Recovery Time (Note 4)	t_{rr}	25		35	ns
Typical Reverse Recovery Time	t_{rr}	20		30	ns
Typical Junction Capacitance (Note 5)	C_T	20			pF
Typical Thermal Resistance (Note 6)	R_{thJA} R_{thJL} R_{thJC}	90 30 25			°C/W
Operating Temperature Range	T_J	-55 to + 150			°C
Storage Temperature Range	T_{STG}	-55 to + 150			°C

Note :

REV-11, Oct-2021, KSGA01

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{rr}=0.25A.
5. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
6. Thermal Resistance junction to Ambient, Lead and Case.

RATING AND CHARACTERISTIC CURVES
ES1D-ES1J

FIG.1- FORWARD CURRENT DERATING CURVE

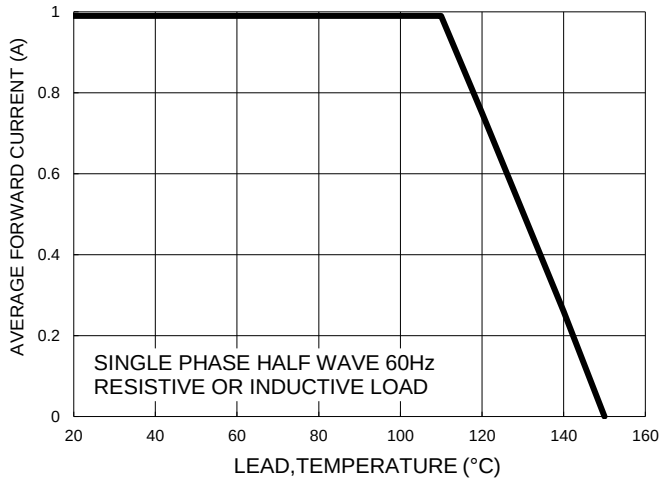


FIG.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

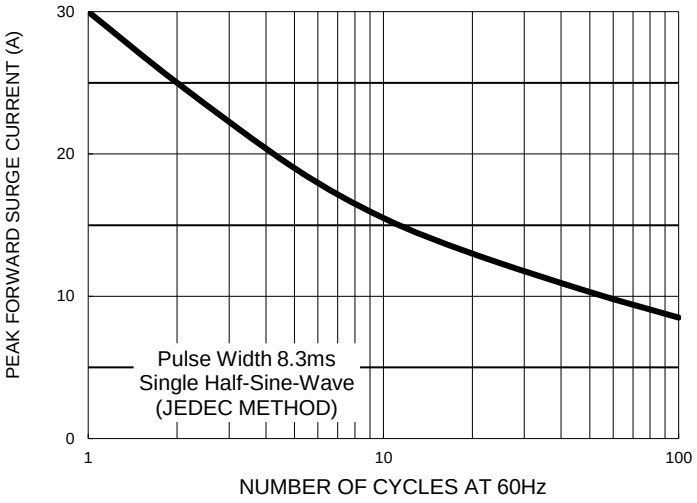


FIG.3- TYPICAL FORWARD CHARACTERISTICS

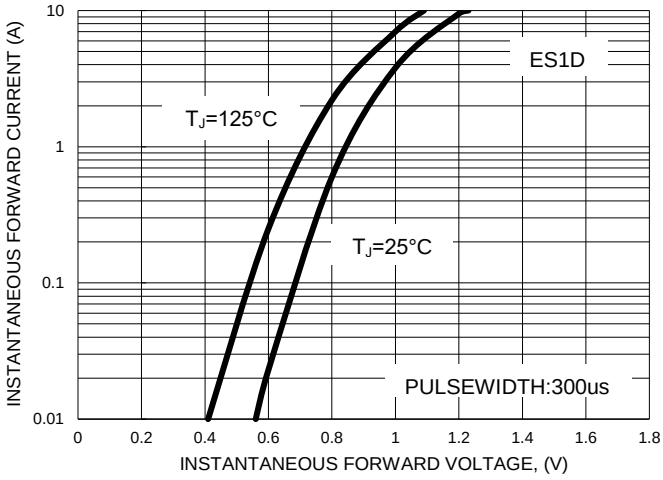


FIG.4- TYPICAL REVERSE CHARACTERISTICS

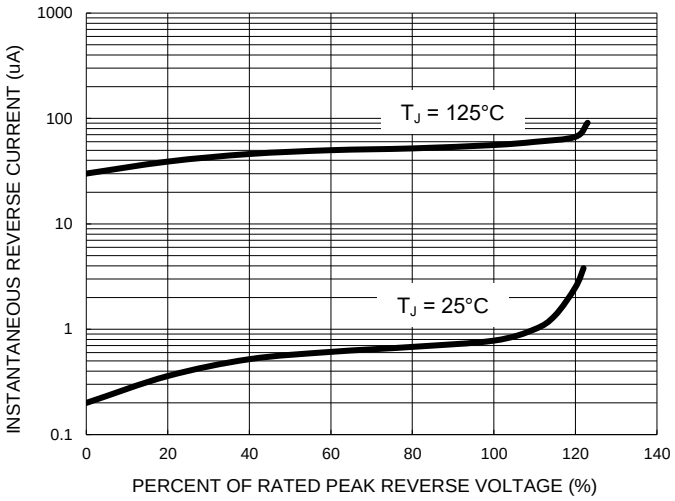


FIG.5- TYPICAL FORWARD CHARACTERISTICS

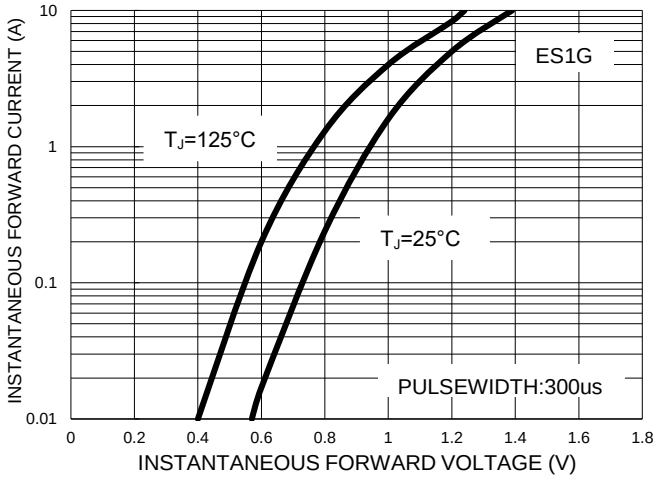
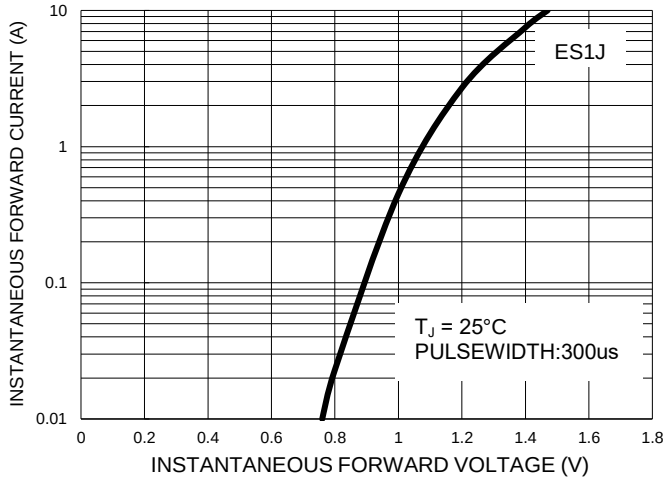


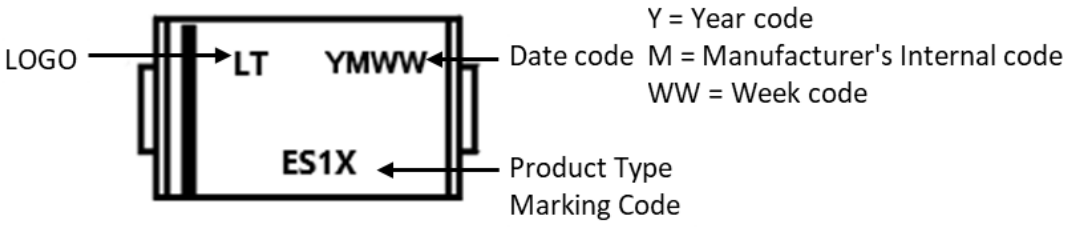
FIG.6- TYPICAL FORWARD CHARACTERISTICS



Ordering Information :

Part Number	Case	Packaging
ES1D_HF	SMA	5000pcs/Reel
ES1G_HF	SMA	5000pcs/Reel
ES1J_HF	SMA	5000pcs/Reel

Marking Information :



IMPORTANT NOTICE

1. DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.

3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.

4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.

5. Diodes products are provided subject to Diodes' Standard Terms and Conditions of Sale (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

6. Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.

7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.

8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

www.diodes.com